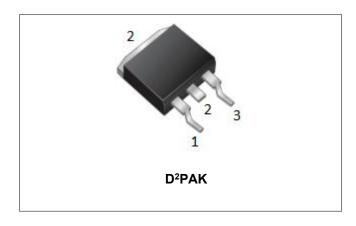






## **MBRB1545CT SCHOTTKY RECTIFIER**



#### **Features**

- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	l <sub>F (AV)</sub>	Tc=131°C, In DC	7.5(Per Leg) 15(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	IFSM	8.3ms, Half Sine pulse	150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.60	0.84	V
(Per Leg) *	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.57	0.72	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.03	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	15	25	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C, f <sub>SIG</sub> = 1MHz	300	400	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	V <sub>R</sub> ≤80%V <sub>RRM</sub> V <sub>R</sub> ≤50%V <sub>RRM</sub>	-55 to +150 -55 to +180 -55 to +200	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>0</sub> JC	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**

Figure 1 Typical Forward Characteristics

(V)

10<sup>1</sup>

25 °C

10<sup>0</sup>

0.2

0.4

0.6

0.8

1.0

1.2

Forward Voltage -V<sub>F</sub>(V)

Figure 2 Typical Reverse Characteristics

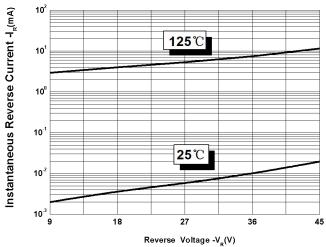
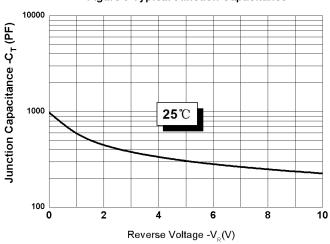


Figure 3 Typical Junction Capacitance



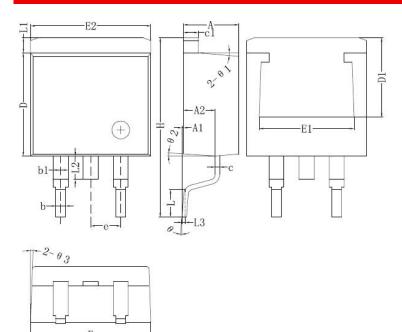
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### Mechanical Dimensions D<sup>2</sup>PAK



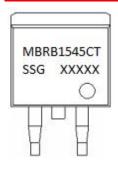
Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

## **Ordering Information**

Device	Package	Shipping
MBRB1545CT	D <sup>2</sup> PAK	800pcs / reel
MBRB1545CTTR	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

 MBR
 = Device Type

 B
 = Package type

 15
 = Forward Current (15A)

 45
 = Reverse Voltage(45V)

 CT
 = Configuration

 SSG
 = SSG

 YY
 = Year

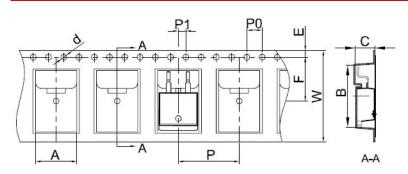
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# Carrier Tape Specification D<sup>2</sup>PAK



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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